16,384-Bit (4,096x4) Bipolar PROM

DISTINCTIVE CHARACTERISTICS

- Ultra-fast access time "A" version (35 ns Max.)
- Platinum-Silicide fuses guarantee high reliability, fast programming and exceptionally high programming yields (typ > 98%)
- AC performance is factory tested utilizing programmed test words and columns
- Voltage and temperature compensated providing extremely flat AC performance over military range
- Member of generic PROM series utilizing standard programming algorithm

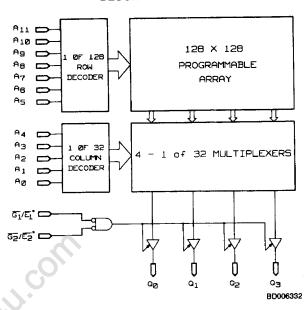
GENERAL DESCRIPTION

The Am27S41 (4,096 words by 4 bits) is a Schottky TTL Programmable Read-Only Memory (PROM).

This device has three-state outputs compatible with lowpower Schottky bus standards capable of satisfying the requirements of a variety of microprogrammable controls, mapping functions, code conversion, or logic replacement. Easy word-depth expansion is facilitated by active LOW $(\overline{G_1} \& \overline{G_2})$ output enables.

As an APL product, this device is also offered in a power-switched version, the Am27PS41.

BLOCK DIAGRAM



*E nomenciature applies only to Am27PS power-switched version.

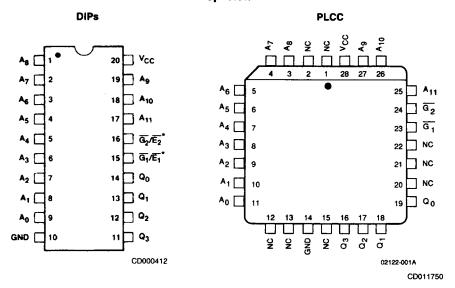
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PRODUCT SELECTOR GUIDE

Part Number	Am27S41A		Am2	Am27PS41		
Address Access Time	35 ns	50 ns	50 ns	65 ns	65 ns	
Operating Range	С	М	С	М	М	

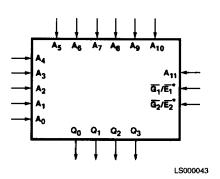
Publication # Rev. Amendment 02122 D /0 Issue Date: January 1969

CONNECTION DIAGRAMS Top View



Note: Pin 1 is marked for orientation.

LOGIC SYMBOL



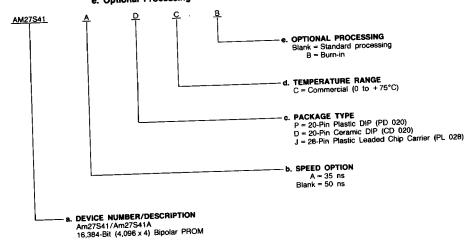
*E nomenclature applies only to Am27PS power-switched version.

ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of: a. Device Number

- b. Speed Option (if applicable)
- c. Package Type
- d. Temperature Range
- e. Optional Processing



Valid Combinations					
AM27S41	PC, PCB, DC, DCB,				
AM27S41A	JC, JCB				

Valid Combinations

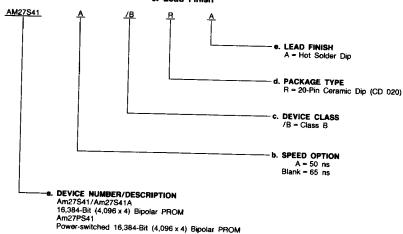
Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

MILITARY ORDERING INFORMATION

APL Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. The order number (Valid Combination) for APL products is formed by a combination of: a. Device Number

- b. Speed Option (if applicable)
- c. Device Class
- d. Package Type
- e. Lead Finish



Valid Combinations							
AM27S41							
AM27S41A	/BRA						
AM27PS41	1						

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations or to check for newly released valid combinations.

Group A Tests

Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

MILITARY BURN-IN

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.

PIN DESCRIPTION

A₀-A₁₁ Address Inputs

The 12-bit field presented at the address inputs selects one of 4,096 memory locations to be read from.

Q₀ - Q₃ Data Output Port

The outputs whose state represents the data read from the selected memory locations.

G₁, G₂ Output Enable

Provides direct control of the Q-output, three-state buffers. Outputs disabled forces all outputs to a floating or highimpedance state. On power-switched version, the disabled state reduces the ICC to ICCD.

Enable =
$$\overline{G_1} \cdot \overline{G_2}$$

Disable = $\overline{G_1} \cdot \overline{G_2}$

V_{CC} Device Power Supply Pin The most positive of the logic power supply pins.

Device Power Supply Pin

The most negative of the logic power supply pins.

FUNCTIONAL DESCRIPTION

Power Switching

The Am27PS41 is a power-switched device, When the chip is selected, important internal currents increase from small idling or standby values to their larger selected values. This transition occurs very rapidly, meaning that access times from the powered-down state are only slightly slower than from the powered-up state. Deselected, ICC is reduced to half its full operating amount. Due to this unique feature, there are special considerations which should be followed in order to optimize performance:

- 1. When the Am27PS41 is selected by a low level on $\overline{E_1}$, a current surge is placed on the V_{CC} supply due to the powerup feature in order to minimize the effects of this current transient, it is recommended that a 0.1 μf ceramic capacitor be connected from pin 20 to pin 10 at each device. (See Figure 1.)
- 2. Address access time (TAVQ1) can be optimized if a chip enable set-up time (TEVAV) of greater than 25 ns is ovserved. Negative set-up times on chip enable (TEVAV < 0) should be avoided. (For typical and worse case characteristics, see Figures 2A and 2B.)

ABSOLUTE MAXIMUM RATINGS

Storage Temperature65 to +150°C Ambient Temperature with
Power Applied55 to +125°C
Supply Voltage0.5 V to +7.0 V
DC Voltage Applied to Outputs
(Except During Programming)0.5 V to +VCC Max.
DC Voltage Applied to Outputs
During Programming21 V
Output Current into Outputs During
Programming (Max. Duration of 1 sec) 250 mA
DC Input Voltage0.5 V to + 5.5 V
DC Input Current30 mA to +5 mA

OPERATING RANGES

Commercial (C) Devices Ambient Temperature (T _A)
Military (M) Devices Case Temperature (T _C)55 to +125°C Supply Voltage (V _{CC})+4.5 V to +5.5 V
Operating ranges define those limits between which the functionality of the device is guaranteed.
Military Products 100% tested at T _C = +25°C, +125°C,

DC CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 1, 2, 3 are tested unless otherwise noted)

and -55°C.

Parameter Symbol	Parameter Description	Test Conditions			Тур.	Max.	Unit
VOH	Output HIGH Voltage V _{CC} = Min., I _{OH} = -2.0 mA V _{IN} = V _{IH} or V _{IL}				- 7	- Huazi	V
VOL	Output LOW Voltage	Vcc = Min., I _{OL} = 16 mA COM'L				0.45	
		VIN = VIH Or VIL	MIL			0.50	v
VIH	Input HIGH Level	Guaranteed input logical HIGH voltaginputs (Note 3)	e for all	2.0			v
VIL	Input LOW Level	Guaranteed input logical LOW voltage inputs (Note 3)	for all			0.8	٧
l _{IL}	Input LOW Current	V _{CC} = Max., V _{IN} = 0.45 V		 		-0.250	
Ін	Input HIGH Current	VCC = Max., VIN = VCC		 - 		40	mA µA
Isc	Output Short-Circuit Current	V _{CC} = Max., V _{OUT} = 0.0 V	COM'L	-20		-90 -90	mA
		(Note 1)	MIL	-15			
lcc	Power Supply Current	Vcc = Max. All inputs = 0.0 V	COM'L			165	mA
	+		MIL			170	
ICCD*	Am27PS Version Power Down Supply Current	V _{CC} = Max V _{E1} = 2.4 V, All other inputs = 0.0 V				85	mA
V _i	Input Clamp Voltage	V _{CC} = Min., I _{IN} = -18 mA				-1.2	
ICEX	Output Leakage Current	V _{CC} = Max.	Vo = Vcc			40	ν μ Α
		VG1 = 2.4 V	Vo = 0.4 V			-40	
CiN	Input Capacitance	V _{IN} = 2.0 V @ f = 1 MHz (Note 2) V _{CC} = 5 V, T _A = 25°C V _{OUT} = 2.0 V @ f = 1 MHz (Note 2) V _{CC} = 5 V, T _A = 25°C			5.0	-40	
COUT	Output Capacitance				8.0		₽F

Notes: 1. Not more than one output should be shorted at a time. Duration of the short circuit test should not be more than one second.

2. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where

SWITCHING CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 9, 10, 11 are tested unless otherwise noted*)

Parameter No. Symbol	Ī			27S Version				27PS Version MIL		
	Parameter		COM'L		MIL					
	Symbol	Description	Version	Min.	Max.	Min.	Max.	Min.	Max.	Unit
1 TAVQV	Address Valid to Output Valid Access Time	A		35		50				
		STD		50		65		65	ns	
2 TGVQZ	Delay from Output Enable Valid to Output Hi-Z	Α		25		30				
		STD		25		30		30	ns	
3 TGVQV	Delay from Output Enable Valid to Output Valid	A		25		30		50		
		STD		25		30		85	ns	
4 TAVQV1	Power Switched Address Valid to Output Valid Access Time (Am27PS Versions only)	A				- 50		- 65		
		STD						85	ns	

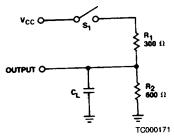
See also Switching Test Circuit.

Notes: 1. Tests are performed with input transition time of 5 ns or less, timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V.

*Subgroups 7 and 8 apply to functional tests.

Sylicand VIH are injure conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.

SWITCHING TEST CIRCUIT



Notes: 1. TAVQV is tested with switch S₁ closed and C_L = 50 pF. TEVAV is defined as chip enable setup time.

2. For the three-state output, TGVQV is tested with C_L = 50 pF to the 1.5 V level; S₁ is open for high-impedance to HIGH tests and closed for high-impedance to LOW tests. TGVQZ is tested with C_L = 5 pF. HIGH to high-impedance tests are made with S₁ open to an output voltage of steady state HIGH -0.5 V; LOW to high-impedance tests are made with S₁ closed to the steady state LOW + 0.5 V level.

SWITCHING WAVEFORMS

KEY TO SWITCHING WAVEFORMS

